



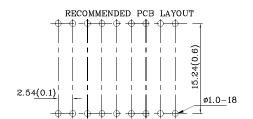
13.8mm (0.543") 14 SEGMENT DUAL DIGIT ALPHANUMERIC DISPLAY

#### **Features**

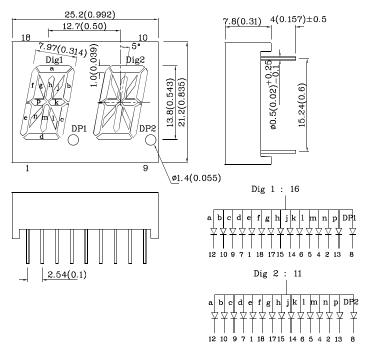
- Low power consumption
- ullet Robust package
- I.C. Compatible
- Standard configuration: Gray face w/ white segments
- $\bullet$  Optional black face provides superior color contrast
- RoHS Compliant







# **Package Schematics**



#### Notes:

1. All dimensions are in millimeters (inches), Tolerance is  $\pm 0.25 (0.01")$  unless otherwise noted.

2. Specifications are subject to change without notice.

Absolute Maximum Ratings (T <sub>A</sub> =25°C)		UG (GaP)	Unit	
Reverse Voltage	$V_{\mathrm{R}}$	5	V	
Forward Current	$I_{\mathrm{F}}$	25	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	140	mA	
Power Dissipation	$P_D$	62.5	mW	
Operating Temperature	$T_{A}$	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +85	-0	
Lead Solder Temperature [2mm Below Package Base]	260°C For 3-5 Seconds			

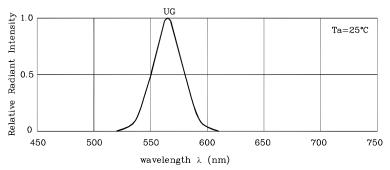
Operating Characteristics (T <sub>A</sub> =25°C)		UG (GaP)	Unit
Forward Voltage (Typ.) (I <sub>F</sub> =10mA)	$V_{\mathrm{F}}$	2	V
Forward Voltage (Max.) (I <sub>F</sub> =10mA)	$V_{\mathrm{F}}$	2.5	V
Reverse Current (Max.) $(V_R=5V)$	$I_R$	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =10mA)	λР	565*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) $(I_F=10\text{mA})$	λD	568*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =10mA)	$\triangle \lambda$	30	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	С	15	pF

Part Number	Emitting Color	Emitting Material	Luminous Inte CIE127-200 (I <sub>F</sub> =10mA) u	07* CIE	velength 127-2007* nm λΡ	Description
			min. t	typ.		
XAUG14A2	Green	GaP		3890 2590*	565*	Common Anode, Rt.Hand Decimal.

\*Luminous intensity value and wavelength are in accordance with CIE127-2007 standards.

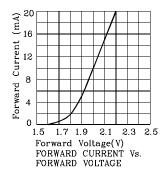
Mar 01,2014

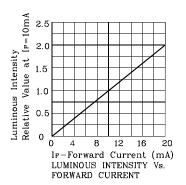


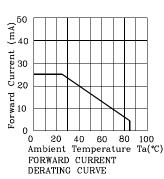


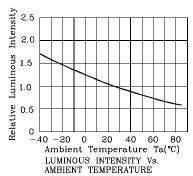
RELATIVE INTENSITY Vs. CIE WAVELENGTH

#### **♦** UG

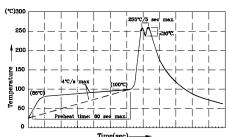








Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



- nmend pre-heat temperature of 105°C or less (as measured with a noccouple attached to the LED pins) prior to immersion in the solder with a maximum solder bath temperature of 250°C wave soldering temperature between 245°C  $\sim$  255°C for 3 sec (5 sec
- 2.Peak wave soldering temperature oetwermax).
  3.Do not apply stress to the epoxy resin (-Pixtures should not incur stress on the during soldering process.
  5.SAC 305 solder alloy is recommended.
  6.No more than one wave soldering pass.

#### Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V

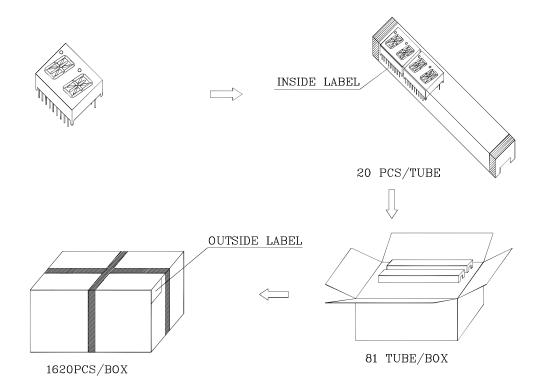
Note: Accuracy may depend on the sorting parameters.





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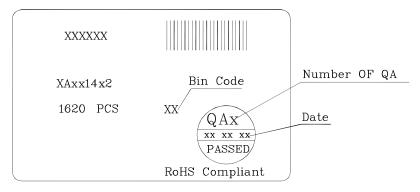
### PACKING & LABEL SPECIFICATIONS



#### Inside Label On IC-tube



### Outside Label On Box



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Mar 01,2014